TEL:805-498-2111 FAX:805-498-3804 WEB:http://www.semtech.com

# AXIAL LEADED HERMETICALLY SEALED FAST RECTIFIER DIODE

- Low reverse recovery time
- Hermetically sealed in Metoxilite fused metal oxide
- Low switching losses
- Low forward voltage drop
- Soft, non-snap off, recovery characteristics

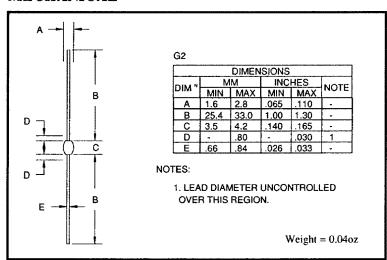
## QUICK REFERENCE DATA

- $V_R = 200 1000V$
- $I_F = 2.00A$
- $t_{rr} = 150 500 nS$
- $I_R = 0.5 \mu A$

### ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

	Symbol	1N5615 S2F	1N5617 S4F	1N5619 S6F	1N5621 S8F	1N5623 S0F	Unit
Working reverse voltage	Vrwm	200	400	600	800	1000	V
Repetitive reverse voltage	Vrrm	200	400	600	800	1000	V
Average forward current (@ 55°C, lead length 0.375")	I <sub>F(AV)</sub>	-		<b>-</b> 2.0 <b>-</b>			Α
Repetitive surge current (@ 55°C in free air, lead length 0.375")	$I_{FRM}$	-		<b>-</b> 6.0 -			A
Non-repetitive surge current $(t_p = 8.3 \text{mS}, @V_R \& T_{jmax})$	IFSM	-		<b>-</b> 25 <b>-</b>		<b></b> →	Α
Storage temperature range	TSTG			55 to +17	75 <del></del>	<del></del>	°C
Operating temperature range	TOP	-		55 to +17	75 ——		°C

#### **MECHANICAL**



These products are qualified to MIL-PRF-19500/429 and are preferred parts as listed in MIL-STD-701. They can be supplied fully released as JAN, JANTX, JANTXV and JANS version. These products are qualified in Europe to

DEF STAN 59-61 (PART 80)/029.

# **ELECTRICAL CHARACTERISTICS** (@ 25°C unless otherwise specified)

	Symbol	1N5615 S2F	1N5617 S4F	1N5619 S6F	1N5621 S8F	1N5623 S0F	Unit
Average forward current max. (pcb mounted; $T_A = 55^{\circ}C$ ) for sine wave for square wave (d = 0.5)	If(AV) If(AV)	<b>4</b>		- 1.00 · - 1.05 ·		<b>→</b>	A A
Average forward current max. $(T_L = 55^{\circ}C; L = 3/8")$ for sine wave for square wave $I^2t$ for fusing $(t = 8.3mS)$ max.	I <sub>F(AV)</sub> I <sub>F(AV)</sub> I <sup>2</sup> t	111					A A A <sup>2</sup> S
Forward voltage drop max. @ $I_F = 1.0A$ , $T_j = 25^{\circ}C$	$V_{\mathbf{F}}$	4		<b>-</b> 1.2 <b>-</b>		<b>→</b>	V
Reverse current max. @ $V_{RWM}$ , $T_j = 25^{\circ}C$ @ $V_{RWM}$ , $T_j = 100^{\circ}C$	I <sub>R</sub> I <sub>R</sub>	<b>-</b>	<u> </u>	- 0.5 - - 25 -	<del>_</del>	<b>→</b>	μΑ μΑ
Reverse recovery time max. $0.5A I_F$ to $1.0A I_R$ . Recovers to $0.25A I_{RR}$ .	t <sub>rr</sub>	150	150	250	300	500	nS
Junction capacitance typ. @ $V_R = 5V$ , $f = 1MHz$	C <sub>j</sub>	27	27	27	18	18	ρF

#### THERMAL CHARACTERISTICS

	Symbol	1N5615 1N5617 1N5619 1N5621 1N5623 S2F S4F S6F S8F S0F	Unit
Thermal resistance - junction to lead Lead length = 0.375" Lead length = 0.0"	R <sub>OJL</sub> Rojl	38	°C/W °C/W
Thermal resistance - junction to amb. on 0.06" thick pcb. 1 oz. copper.	R <sub>0JA</sub>	95	°C/W

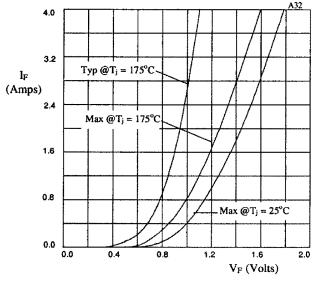
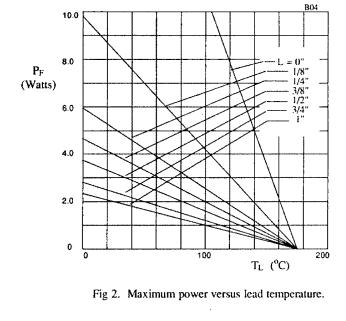


Fig 1. Forward voltage drop as a function of forward current.



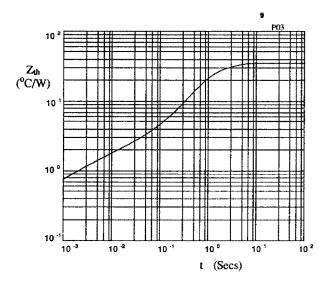


Fig 3. Transient thermal impedance characteristic.

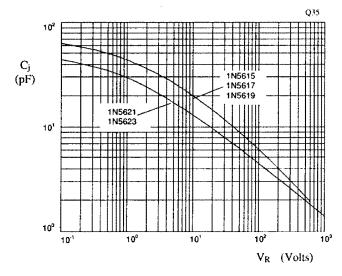


Fig 4. Typical junction capacitance as a function of reverse voltage.

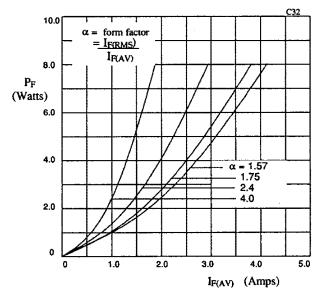


Fig 5. Forward power dissipation as a function of forward current, for sinusoidal operation.

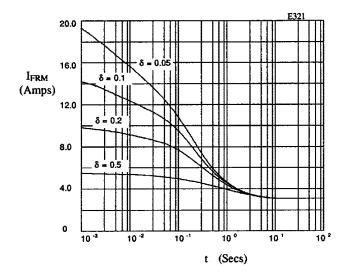


Fig 7. Typical repetitive forward current as a function of pulse width at  $55^{\circ}C$ ;  $R_{\theta JL} = 35\ ^{\circ}C/W$ ;  $V_{RWM}$  during  $1 - \delta$ .

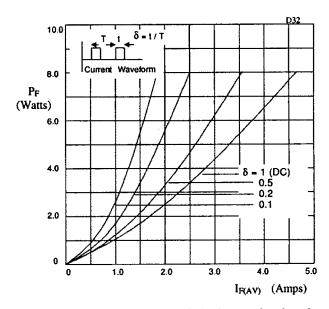


Fig 6. Forward power dissipation as a function of forward current, for square wave operation.

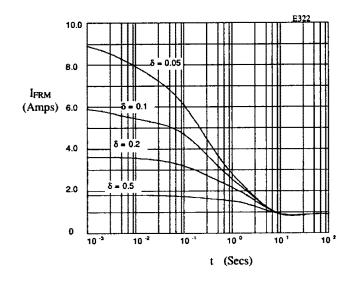


Fig 8. Typical repetitive forward current as a function of pulse width at  $100^{\circ}$ C;  $R_{\theta JL} = 95$  °C/W;  $V_{RWM}$  during  $1 - \delta$ .